

# **Application Note: SY6703**

# **High Efficiency H-Bridge Motor Driver IC**

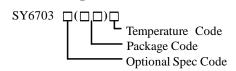
### **General Description**

The SY6703 is a dual H-bridge motor driver solution for toys, printers, and other mechatronic applications. The SY6703 operates with a power-supply voltage range from 2.5V to 16V, and 1.5A RMS maximum output current.

The device can drive two DC brush motors, a bipolar stepper motor, solenoids, or other inductive loads. The highly integrated H-bridge driver block consists of two H-bridges with internal logic control, gate drive, over current protection and charge pump circuit. Each H-bridge includes circuitry to regulate or limit the winding current.

The SY6703 provides internal shutdown functions with a fault output pin are provided for over current protection, short circuit protection, under voltage lockout and thermal shutdown. A low-power sleep mode is also provided. The device is packaged in two different types: a 16-pin TSSOP, a 16-pin QFN package.

# **Ordering Information**



Ordering Number	Package type	Note
SY6703HFC	TSSOP-16E	
SY6703QIC	QFN4×4-16	

#### **Features**

- Dual H-bridge Motor Driver
- Maximum Drive Current of 1.5A RMS Current for Each H-bridge
- Power Supply Voltage Range from 2.5V to 16V
- PWM (IN/IN) Interface
- PWM Winding Current Regulation/Limit
- Internal OCP/SCP/UVL and thermal shutdown
- Multiple Packages Choice: TSSOP-16E/QFN4x4-16

# **Applications**

- POS Printers
- DSLR Lenses
- Video Security Cameras
- Toys
- Robotics
- Game Machines
- Office Automation Machines

# **Typical Applications**

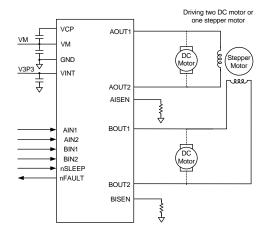
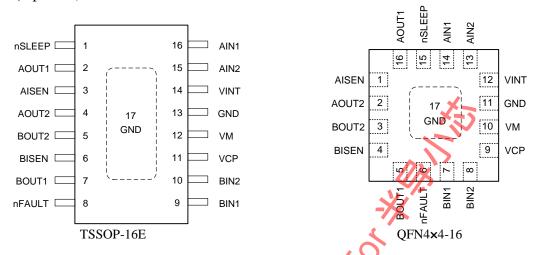


Figure 1. Schematic Diagram



# Pinout (top view)



Part Number	Package type	Top Mark <sup>®</sup>
SY6703HFC	TSSOP-16E	AZRxyz
SY6703QIC	QFN4×4-16	BGSxyz

Note ①: x = year code, y = week code, z = lot number code.

Note : x=year code, y=week code, z= lot number code.					
Name Number		nber	Decarintian		
Name	TSSOP-16E	QFN4 <b>x</b> 4-16	Description		
CI EED	1	1.5	Sleep mode pin Logic low puts device in low-power sleep mode, this		
nSLEEP	P   1   15		pin has a internal pull-down resistor		
AOUT1	2	16	Bridge A output 1 pin. Connect this pin to motor winding.		
			Bridge A current sense pin. Connect a resistor between this pin and		
AISEN	3	1	GND for current control, or connect to GND if current control is not		
			needed.		
AOUT2	4	2	Bridge A output 2 pin. Connect this pin to motor winding.		
BOUT2	5	3	Bridge B output 2 pin. Connect this pin to motor winding.		
			Bridge B current sense pin. Connect a resistor between this pin and		
BISEN	6	4	GND for current control, or connect to GND if current control is not		
			needed		
BOUT1	7	5	Bridge B output 1 pin. Connect this pin to motor winding.		
nFAULT	8	6.0	Fault state output pin. Logic low if fault is detected.		
DIMI	0		Bridge B input 1 pin. Control the state of bridge B, this pin has an		
BIN1	9	-0	internal pull-down resistor.		
DIMO	10	( )	Bridge B input 2 pin. Control the state of bridge B, this pin has an		
BIN2 10		8	internal pull-down resistor		
VCD	11	9	Internal charge pump voltage for high side gate driver. Connect a		
VCP	11	<b>3</b> , 9	ceramic capacitor to VM.		
VM	12	10	Motor power supply pin. Decouple this pin to GND pin with 10uF		
VIVI		10	ceramic cap.		
GND	13	11	Device ground pin.		
VINT	1.4	12	Internal logic and driver supply. Connect this pin with a ceramic		
VIIVI	14 12		capacitor to GND.		
AIN2	AINI2 15 1		Bridge a input 2 pin. Control the state of bridge A, this pin has an		
AIINZ	15	13	internal pull-down resistor.		
AIN1	16	14	Bridge A input 1 pin. Control the state of bridge A, this pin has an		
AIINI		14	internal pull-down resistor.		
GND	17	17	Ground pin for thermal dissipation.		



# **Block Diagram**

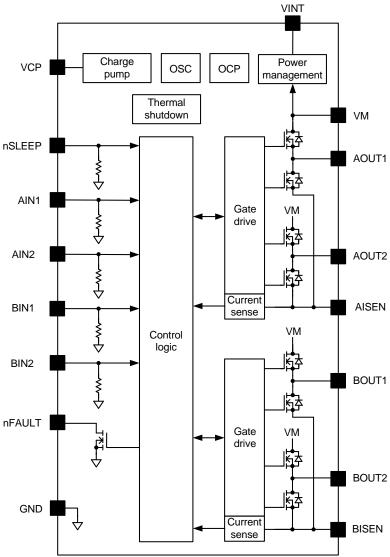


Figure 2. Block Diagram



Absolute Maximum Ratings (Note 1)	
VM, OUT1, OUT2, nFAULT, nSLEEP	16V
VCP	
xIN1, xIN2	0.3V to 6V
xISEN	
Junction Temperature (T <sub>J</sub> )	
Storage Temperature	
Package Thermal Resistance	
$\theta_{JA}$ (Note 2), TSSOP-16E/QFN4×4-16	41/38 ℃/W
$\theta_{\text{JC\_TOP}}$ , TSSOP-16E/QFN4×4-16	33/35 ℃/W
<b>Recommended Operating Conditions</b>	
VM, nSLEEP	2.5V to 12V
xIN1, xIN2	-0.1V to 5V
H-Bridge Output RMS Current (Note3) (Package TSSOP-16E/QFN4x4-16)	0A to 1.5A
Junction Temperature Range	

## **Electrical Characteristics**

 $(T_A = 25 \text{ °C}, VM=5V, \text{ unless otherwise specified})$ 

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Power Supplies						
VM Operating Supply Current	$I_{VM}$	VM=5V, xIN=0V, xIN2=0V		0.65	1.2	mA
VM Sleep Mode Current	$I_{VMS}$	nSLEEP=0V, VM=5V		1.8	2.5	μΑ
VM UVL Voltage	V <sub>UVLO RISE</sub>			2.0		V
VIVI OVE VOItage	V <sub>UVLO FALL</sub>	V <sub>UVLO FALL</sub> VM Falling		1.9		V
VINT	$V_{INT}$	nSLEEP=3V,VM=5V	3	3.3		V
Logic Level Input						
Input Low Voltage	$V_{IL}$	nSLEEP			0.4	V
input Low Voltage	▼ IL	All other pins			0.7	•
Input High Voltage	$V_{ m IH}$	nSLEEP	2.5			V
1 0	▼ IH	All other pins	2.2			v
Input Low Current	$I_{ m IL}$	$V_{IN}=0V$			1	μΑ
Input High Current	$I_{IH}$	V <sub>IN</sub> =3.3V, nSLEEP		5.3	12	μA
	*IH	V <sub>IN</sub> =3.3V, all except nSLEEP		18	30	μΛ
Input Deglitch Time	$t_{DEG}$	(Note 4)		450		ns
nFAULT Output (Open-Drain Out						
Output Low Voltage	V <sub>OL</sub>	I <sub>O</sub> =5mA			0.2	V
Output High Leakage Current	$I_{OH}$	V <sub>0</sub> =3.3V			1	μΑ
H-Bridge MOSFETs						
High Side MOSFETs On Resistance	D	$V_M=5V$ , $I_O=500$ mA, $T_J=25$ °C		260		mΩ
Low Side MOSFETs On Resistance	$R_{dson}$	$V_{\rm M}$ =5V, $I_{\rm O}$ =500mA, $T_{\rm J}$ =25°C		220		1112.2
Off-State Leakage Current	$I_{OFF}$	$V_M=5V$ , VOUT= $0V$ , $T_J=25$ °C			±1	μA
Motor Driver						
Current Control PWM Frequency	$f_{PWM}$	Internal PWM Frequency		50		kHz
Rise Time	$t_R$	$V_M=5V,16\Omega$ to GND, 10% to		60		ns
Fall Time	$t_{\mathrm{F}}$	90% V <sub>M</sub> ,Note4		50		ns
Propagation Delay INx to OUTx	t <sub>PROP</sub>	V <sub>M</sub> =5V, Note4		0.35		μs





Dead Time	$t_{ m DEAD}$	V <sub>M</sub> =5V, Note4		100		ns
Protection						
Output Over Current Limit	$I_{OCP}$		1.8	3		Α
Over Current Retry Time	$t_{OCPR}$			1.5		ms
OCP Deglitch Time	$t_{ m DEG}$	Note 4		180		ns
Thermal Shutdown Temperature	$T_{SD}$			160		$^{\circ}$
Thermal Shutdown hysteresis	T <sub>HYS</sub>			20		$^{\circ}$
Current Control						
xISEN Trip Voltage	$V_{TRIP}$		160	200	240	mV
Current Sense Blanking Time	$t_{\rm BLANK}$			3.0		μs

**Note 1**: Stresses beyond the "Absolute Maximum Ratings" may cause permanent damage to the device. These are for stress ratings only. Functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

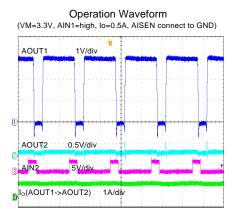
Note 2:  $\theta_{JA}$  is measured in the natural convection at  $T_A = 25$  °C on a low effective single layer thermal conductivity test board of JEDEC 51-3 thermal measurement standard.

Note 3: Power dissipation and thermal limits must be observed.

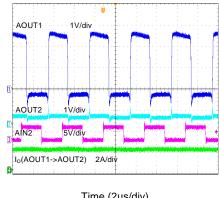
Note 4: Guaranteed by design.



# **Typical performance characteristics**

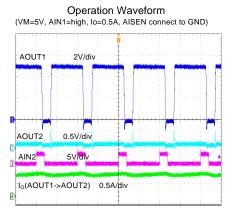


Time (2µs/div)

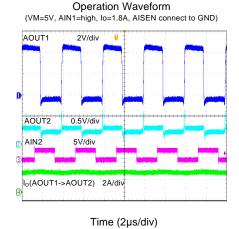


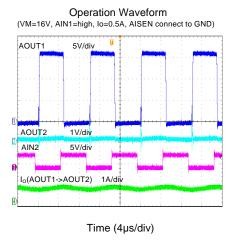
Operation Waveform (VM=3.3V, AIN1=high, Io=1.8A, AISEN connect to GND)

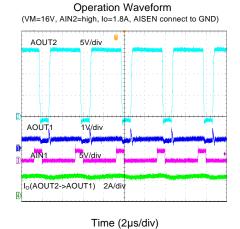
Time (2µs/div)



Time (2µs/div)

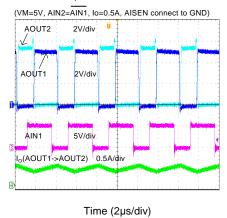




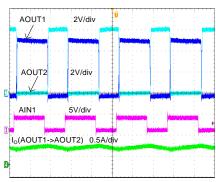




#### Operation Waveform

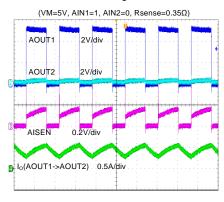


Operation Waveform (VM=5V, AIN2=0, Io=0.5A, AISEN connect to GND)



Time (4µs/div)

#### **Current Regulation**



Time (10µs/div)



### Functional Description PWM Motor Drivers

SY6703 contains two identical H-bridge motor drivers with current-control PWM circuitry. A block diagram of the circuitry is shown below:

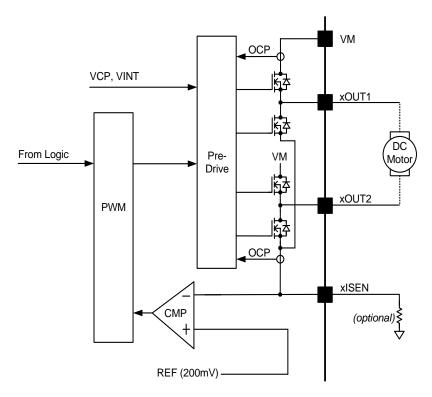


Figure 3. Motor Control Circuitry

#### **H-Bridge Driving Control**

The Bridge is controlled by a PWM input interface, also called IN/IN interface. The following table shows the control logic of the device:

xIN1	xIN2	xOUT1	xOUT2	Function
0	0	Z	Z	Coast/Fast Decay
0	1	L	Н	Reverse
1	0	Н	L	Forward
1	1	L	L	Brake/Slow Decay

Table 1 H-Bridge Logic

The inputs can also be used for PWM control of the motor speed. When controlling a winding with PWM and the drive current is interrupted, the inductive nature of the motor requires that the current must continue to flow. This is called recirculation current. To handle this recirculation current, the H-bridge can operate in two different states, fast decay or slow decay. In fast decay mode, the H-bridge is disabled and recirculation current flows through the body diodes; in slow decay, the motor winding is shorted.



For PWM using fast decay, the PWM signal is applied to one xIN pin while the other is held low; to use slow decay, one xIN pin is held high.

Table 2 PWM	Control	of Motor	Speed
-------------	---------	----------	-------

xIN1	xIN2	Function
PWM	PWM 0 Forward PWM, Fast Decay	
1	PWM	Forward PWM, Slow Decay
0	PWM	Reverse PWM, Fast Decay
PWM	1	Reverse PWM, Slow Decay

Figure 4 shows the current paths in different drive and decay modes.

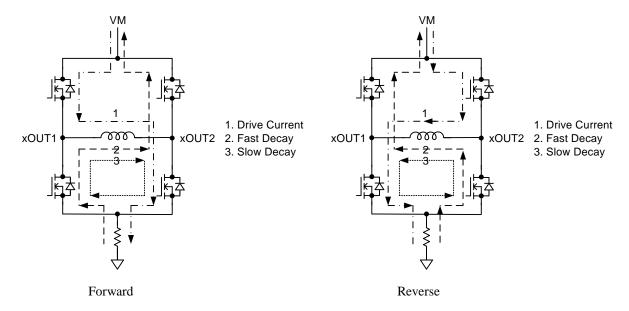


Figure 4. Decay Mode

#### **Current Control**

The current through the motor windings may be limited, or controlled, by a fixed-frequency PWM current regulation, or current chopping. For DC motors, current control is used for limiting the start-up and stalling current of the motor. For stepper motors, current control is used frequently at all times.

When an H-bridge is enabled, current rises through the winding at a rate dependent on the DC voltage and inductance of the winding. If the current reaches the current chopping threshold, the bridge will disable the current until the beginning of the next PWM cycle. Note that immediately after the current is enabled, the voltage on the xISEN pin is ignored for a fixed period of time before enabling the current sense circuitry. This blanking time is fixed at about  $3.1\mu s$ . This blanking time also sets the minimum on time of the PWM when operating in current chopping mode.

The PWM chopping current is set by a comparator which compares the voltage across a current sense resistor connected to the xISEN pins with a reference voltage. The reference voltage is fixed at 200 mV.

The chopping current is calculated in Equation 1.

$$I_{CHOP} = \frac{200mV}{R_{SENSE}} \tag{1}$$

Example:



If a 1 $\Omega$  sense resistor is used, the chopping current will be 200 mV/1  $\Omega$  = 200 mA.

Once the chopping current threshold is reached, the H-bridge will switch to slow decay mode. Winding current is re-circulated by enabling both of the low-side FETs in the bridge. This state is held until the beginning of the next fixed-frequency PWM cycle.

Note that if current control is not needed, the xISEN pins should be connected directly to ground.

#### **Sleep Mode**

Driving nSLEEP low will put the device into a low power sleep state. In this state, the H-bridges are disabled, the gate drive charge pump is stopped, all internal logic is reset, and all internal clocks are stopped. All inputs are ignored until nSLEEP returns inactive high. When returning from sleep mode, some time needs to pass before the motor driver becomes fully operational. To make the board design simple, the nSLEEP can be pulled up to the supply (VM).

#### **Over Current Protection (OCP)**

An analog current limit circuit on each FET limits the current through the FET by limiting the gate drive. If this analog current limit persists for longer than the OCP deglitch time, all FETs in the H-bridge will be disabled and the nFAULT pin will be driven low. The driver will be re-enabled after the OCP retry period  $(t_{OCP})$  has passed. nFAULT becomes high again at this time. If the fault condition is still present, the cycle repeats. If the fault is no longer present, normal operation resumes. Please note that only the H-bridge in which the OCP is detected will be disabled while the other bridge will function normally.

Over current conditions are detected independently on both high and low side devices; i.e., a short to ground, supply, or across the motor winding will all result in an over current shutdown. Over current protection does not use the current sense circuitry for PWM current control, it works even without presence of the xISEN resistors.

#### Thermal Shutdown (TSD)

If the die temperature exceeds safe limits, all MOSFETs in the H-bridge will be disabled. Once the die temperature has fallen to a safe level, operation automatically resumes.

#### **Under Voltage Lockout (UVLO)**

If at any time the voltage on the VM pin falls below the under voltage lockout threshold voltage, all circuitry in the device will be disabled, and all internal logic will be reset. Operation will resume when VM rises above the UVLO threshold. nFAULT is driven low in the event of an under voltage condition.

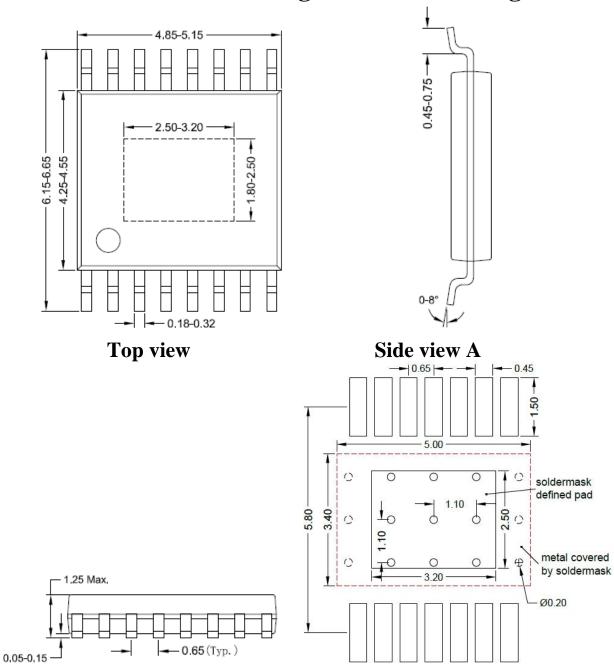
#### **Maximum Output Current**

In actual operation, the maximum output current achievable with a motor driver is a function of die temperature. This in turn is greatly affected by ambient temperature and PCB design. Basically, the maximum motor current will be the amount of current that results in a power dissipation level that, along with the thermal resistance of the package and PCB, keeps the die at a low enough temperature to stay out of thermal shutdown.

The dissipation ratings given in the datasheet can be used as a guide to calculate the approximate maximum power dissipation that can be expected to be possible without entering thermal shutdown for several different PCB constructions. However, for accurate data, the actual PCB design must be analyzed via measurement or thermal simulation.



# **TSSOP16E Package Outline Drawing**



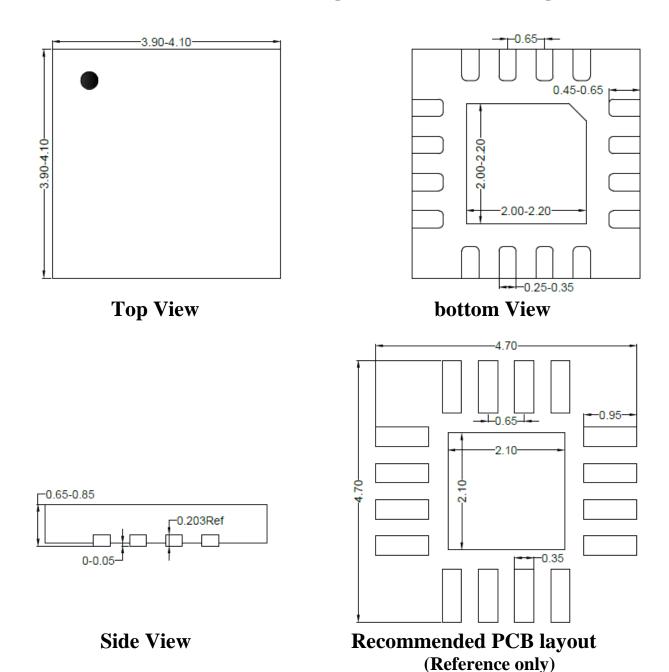
Side view B

Recommended PCB layout (Reference only)

Notes: All dimension in millimeter and exclude mold flash & metal burr.



# QFN4x4-16 Package Outline Drawing

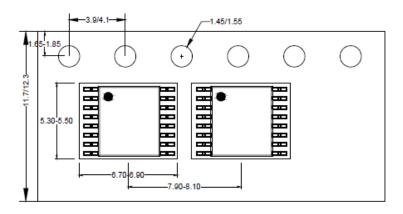


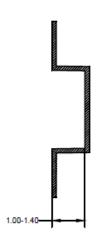
Notes: All dimension in millimeter and exclude mold flash & metal burr.



# **Taping & Reel Specification**

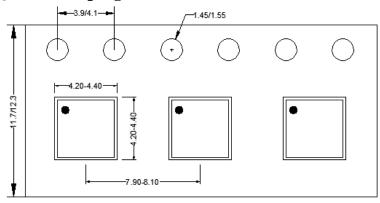
# 1. TSSOP16E Taping orientation





Feeding direction ----

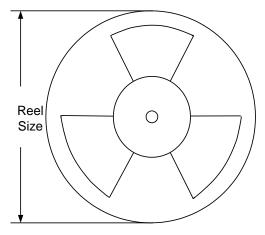
# 2. QFN4x4 Taping orientation



Feeding direction →



# 3. Carrier Tape & Reel specification for packages



Package types	Tape width	Pocket	Reel size	Trailer *	Leader *	Qty per reel
- meange types	(mm)	pitch(mm)	(Inch)	length(mm)	length (mm)	(pcs)
TSSOP16E	12	8	13"	400	400	3000
QFN4x4	12	8	13"	400	400	5000

4. Others: NA



# **Revision History**

The revision history provided is for informational purpose only and is believed to be accurate, however, not warranted. Please make sure that you have the latest revision.

Date	Revision	Change
June. 4, 2020	Revision 0.9A	Add the Recommended PCB layout information in page 11 and 12
July 10, 2018	Revision 0.9	Initial Release



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